

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic Drain-Source Voltage			Symbol	Value	Unit V V
			V _{DSS}	30 ±12	
Gate-Source Voltage	V _{GSS}				
Continuous Drain Current (Note 5) $V_{GS} = 10V$	Steady State	T _A = +25°C T _A = +85°C	I _D	8.8 6.3	А
Continuous Drain Current (Note 6) V _{GS} = 10V	$t \leq 10 s$	T _A = +25°C T _A = +85°C	ID	11.7 8.5	А
Continuous Drain Current (Note 6) $V_{GS} = 4.5V$	$t \leq 10 s$	T _A = +25°C T _A = +85°C	ID	10.8 7.8	А
Pulsed Drain Current (Note 7)			I _{DM}	90	А
Avalanche Current (Notes 7 & 8)			I _{AR}	13	А
Repetitive Avalanche Energy (Notes 7 & 8) L = 0.3mH			E _{AR}	25.4	mJ

Thermal Characteristics

Characteristic		Symbol	Value	Unit
Power Dissipation (Note 5)		PD	1.54	W
Thermal Resistance, Junction to Ambient $@T_A = +25^{\circ}C$ (Note 5)		R _{0JA}	81	°C/W
Power Dissipation (Note 6)		PD	2.8	W
Thermal Resistance, Junction to Ambient @ $T_A = +25^{\circ}C$ (Note 6)		Reja	45	°C/W
Operating and Storage Temperature Range		TJ, T _{STG}	-55 to +150	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

		4							
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition			
OFF CHARACTERISTICS (Note 9)									
Drain-Source Breakdown Voltage	BV _{DSS}	30	-	-	V	$V_{GS} = 0V, I_D = 1mA$			
Zero Gate Voltage Drain Current	IDSS	-	-	0.1	mA	$V_{DS} = 30V, V_{GS} = 0V$			
Gate-Source Leakage	IGSS	-	-	±100	nA	$V_{GS} = \pm 12V$, $V_{DS} = 0V$			
ON CHARACTERISTICS (Note 9)									
Gate Threshold Voltage	V _{GS(TH)}	1.0	-	2.3	V	$V_{DS} = V_{GS}$, $I_D = 250 \mu A$			
Static Drain-Source On-Resistance	P	-	9.5	12.5	mΩ	V _{GS} = 10V, I _D = 11.7A			
Static Drain-Source On-Resistance	R _{DS(ON)}	-	11.5	14.8	1115.2	V _{GS} = 4.5V, I _D = 10.8A			
Forward Transfer Admittance	Y _{fs}	-	22	-	s	$V_{DS} = 5V, I_D = 11.7A$			
Diode Forward Voltage	V _{SD}	-	0.38	0.6	V	$V_{GS} = 0V, I_{S} = 1A$			
Maximum Body-Diode + Schottky Continuous Current	Is	-	-	5	А	-			
DYNAMIC CHARACTERISTICS (Note 10)									
Input Capacitance	Ciss	-	1849	-	pF	V _{DS} =15V, V _{GS} = 0V, f = 1.0MHz			
Output Capacitance	Coss	-	158	-	pF				
Reverse Transfer Capacitance	C _{rss}	-	123	-	pF				
Gate Resistance	Rg	0.54	2.68	4.82	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$			
Total Gate Charge (V _{GS} = 4.5V)	Qq	-	18.5	-	nC				
Total Gate Charge (V _{GS} = 10V)	Qg	-	43	-	nC				
Gate-Source Charge	Q _{gs}	-	4.7	-	nC	V _{DS} = 15V, I _D = 11.7A			
Gate-Drain Charge	Q _{gd}	-	4.0	-	nC	1			
Turn-On Delay Time	t _{D(ON)}	-	6.62	-	ns				
Turn-On Rise Time	t _R	-	8.73	-	ns	V _{GS} = 10V, V _{DS} = 10V,			
Turn-Off Delay Time	tD(OFF)	-	36.41	-	ns	$R_g = 3\Omega, R_L = 1.2\Omega$			
Turn-Off Fall Time	t _F	-	4.69	-	ns				

Notes: 5. Device mounted on FR-4 PCB with minimum recommended pad layout. The value in any given application depends on the user's specific board design. 6. Device mounted on 1" x 1" FR-4 PCB with high coverage 1 oz. Copper, single sided, device is measured at t ≤ 10s.

7. Repetitive rating, pulse width limited by junction temperature.

8. I_{AR} and E_{AR} ratings are based on low frequency and duty cycles to keep $T_J = +25^{\circ}C$.

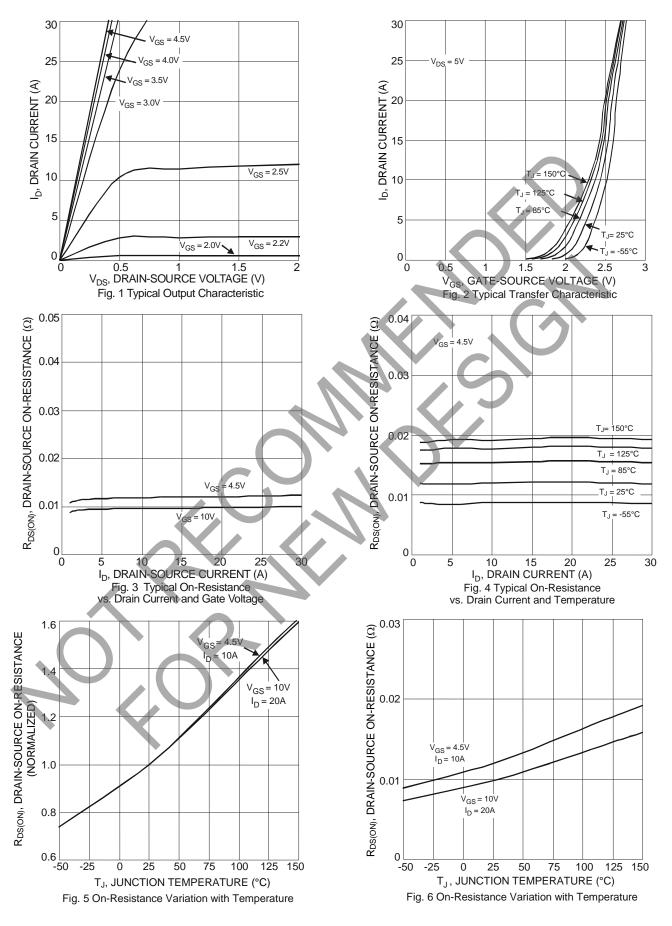
9. Short duration pulse test used to minimize self-heating effect.

10. Guaranteed by design. Not subject to production testing.



NOT RECOMMENDED FOR NEW DESIGN-NO ALTERNATE PART

DMG4710SSS

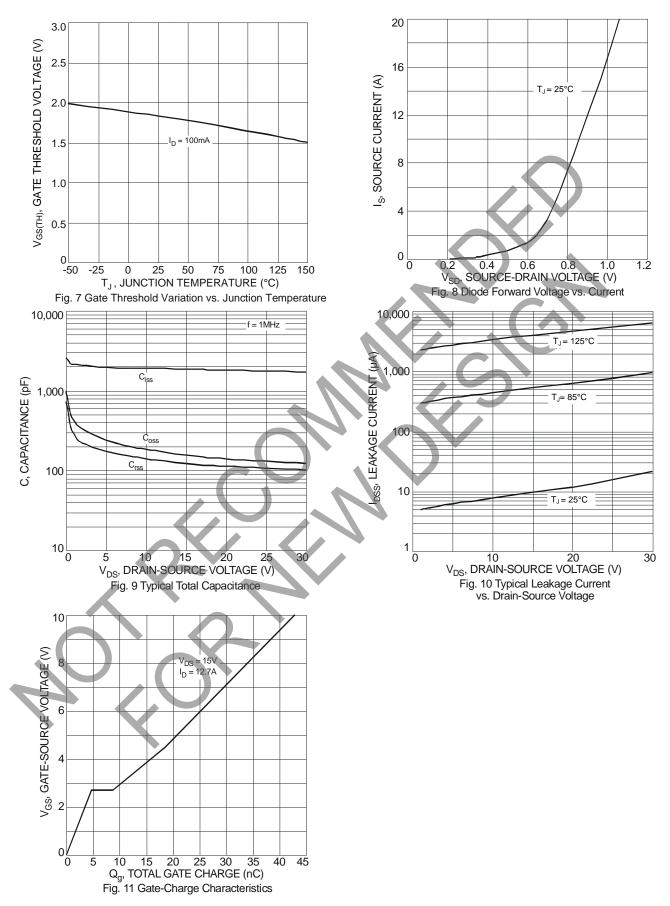


DMG4710SSS Document number: DS32055 Rev. 8 - 3 Downloaded from Arrow.com.



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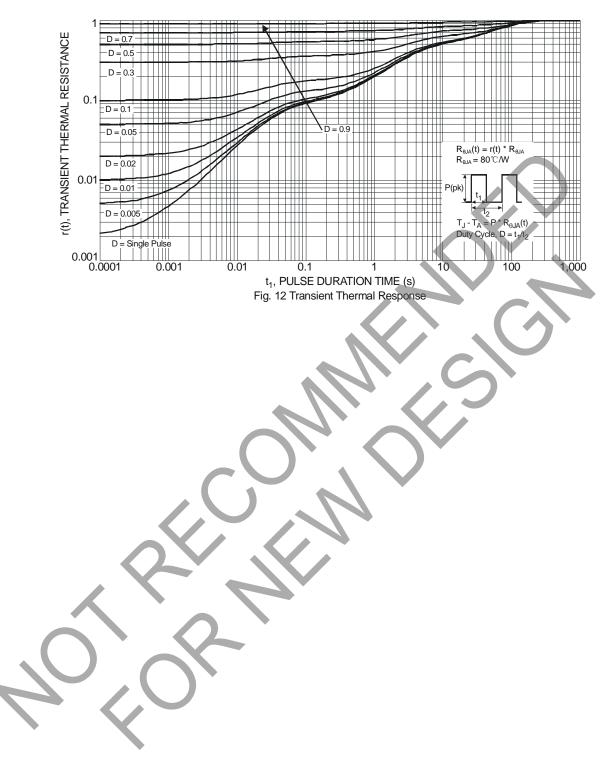
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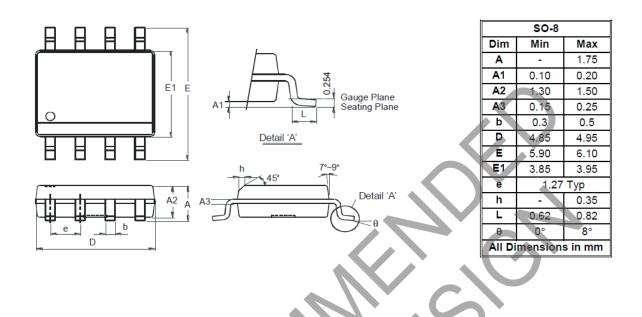
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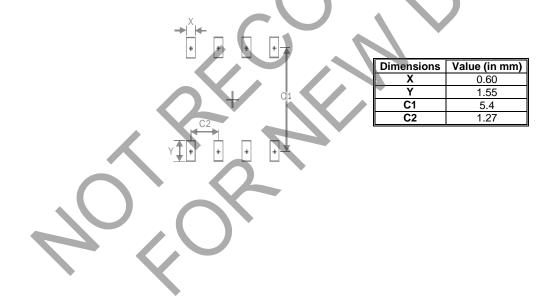
Package Outline Dimensions

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Suggested Pad Layout

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